B

PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

	"" THE OTHIED OTHEOT ATENT	AND INADLIMANN OFFICE
In Re	Patent Application of:)
	Min-hwa Chi))Examiner: Kang, Donghee ₁
Applic	cation No. 09/865,929) Art Unit: 2811
Filed:	May 24, 2001) / / //
For:	TRANSISTOR AND LOGIC CIRCUIT ON THIN SILICON-ON-INSULATOR WAFERS BASED ON GATE INDUCED LEAKAGE CURRENTS	Match & Macons
Attn: C	ant Commissioner for Patents Chief Draftsperson ington, D.C. 20231	i diga.
RI	EQUEST FOR APPROVAL OF DRAWING	G CHANGE UNDER 37 C.F.R. § 1.121
Sir:		
	Applicants respectfully request approva	l of new drawing for Fig. 10A for the
above-	-identified application as enclosed.	
	Respectfully subm	nitted,
	BLAKELY, SOKO	LOFF, TAYLOR & ZAFMAN LLP
Dated:	Jan Jarol Little Reg. No. 41,181	l Lux
Sevent Los An	Wilshire Blvd. th Floor ngeles, CA 90025-1026 292-8600	
I hereby ce postage in	ertify that this correspondence is being deposited with the Unit an envelope addressed to the Assistant Commissioner for Pate April 10, 2003 (Date of Deposit)	ed States Postal Service as first class mail with sufficient nts, Washington, D. C. 20231 on
(Luci M. Arevale Types or prince of person making correspondence)	
	(Signature of person mailing correspondence)	

5/00